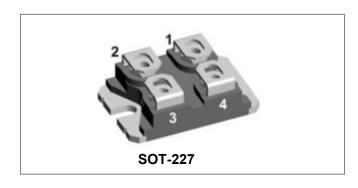






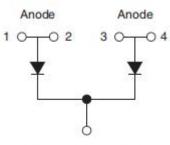
# SKMS320-100 High Voltage Power Schottky Rectifier



#### **Features**

- International standard package SOT-227
- Epoxy meets UL 94V-0
- Extremely low switching losses
- Low I<sub>RM</sub> -values
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Circuit Diagram**



Base common cathode

### **Applications**

- Rectifiers in switch mode power Supplies(SMPS)
- Free wheeling diode in low voltage Converters

### **Advantages**

- · High reliability circuit operation
- Low voltage peaks for reduced Protection circuits
- Low noise switching
- Low losses

## **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	100	V
Average Rectified Forward Current in DC	I <sub>F(AV)</sub>	T <sub>C</sub> =103°C	160(Per Leg) 320(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current (Per Leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse,Tc=25°C	1400	Α

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •







### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V <sub>F1</sub>	@ 160A, Pulse, T <sub>J</sub> = 25 °C	0.81	0.98	V
	V <sub>F2</sub>	@ 160A, Pulse, T <sub>J</sub> = 125 °C	0.66	0.81	V
Reverse Current(Per Leg)*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25 °C	0.001	4	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 125 °C	7	40	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	2850	-	pF

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

## **Thermal-Mechanical Specifications:**

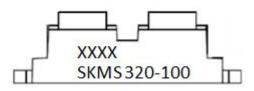
Characteristics	Symbol	Condition	Specification	Units	
Junction Temperature	TJ	-	-55 to +150	°C	
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C	
Thermal Resistance Junction to Case(Per Leg)	R <sub>θJC</sub>	DC operation	0.3	°C/W	
Thermal Resistance Junction to Case(Peg Device)	R <sub>θJC</sub>	DC operation	0.15	°C/W	
Mounting torque(M4)	Mp		1.1-1.5/9-13	Nm/	
Terminal connection torque(M4)	IVID	-	1.1-1.5/9-13	lb.in.	
Typical Approximate Weight	wt	-	30	g	

## **Ordering Information**

Device	Package	Shipping
SKMS320-100	SOT-227	26nas /DLILI/
	(Pb-Free)	36pcs /BULK

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

# **Marking Diagram**



#### Where XXXX is YYWW

S = SMC's Power Module
K = SOT-227 Package
M = Circuit Configuration
S = Schottky Rectifier
320 = Forward Current (320A)
100 = Reverse Voltage (100V)

YY = Year WW = Week







# **Ratings and Characteristics Curves**

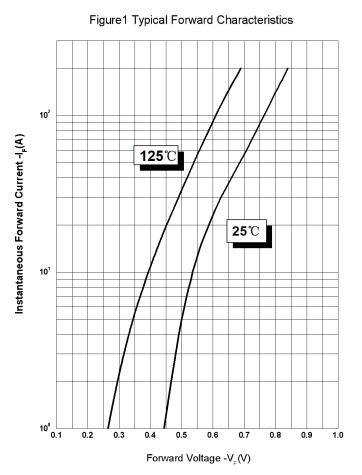
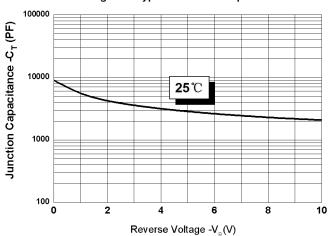


Figure 2 Typical Reverse Characteristics 10<sup>2</sup> Instantaneous Reverse Current -IR(uA) **125℃** 10<sup>1</sup> 10<sup>0</sup> 10<sup>-1</sup> 10-2 25℃ 10<sup>-3</sup> 40 60 80 100 Reverse Voltage -V<sub>R</sub>(V)

Figure 3 Typical Junction Capacitance

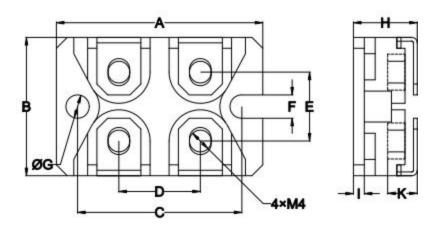








# **Mechanical Dimensions SOT-227(Millimeters)**



SYMBOL	Dimensions in millimeters		
	Min.	Max.	
Α	37.8	38.2	
В	24.8	25.21	
С	29.9	30.55	
D	14.5	15.5	
E	12.2	13.45	
F	4.1	4.31	
G	φ4.1	φ4.31	
Н	11	12.5	
I	1.9	2.1	
K	4.3	6.5	







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